Model 30911 Technical Description

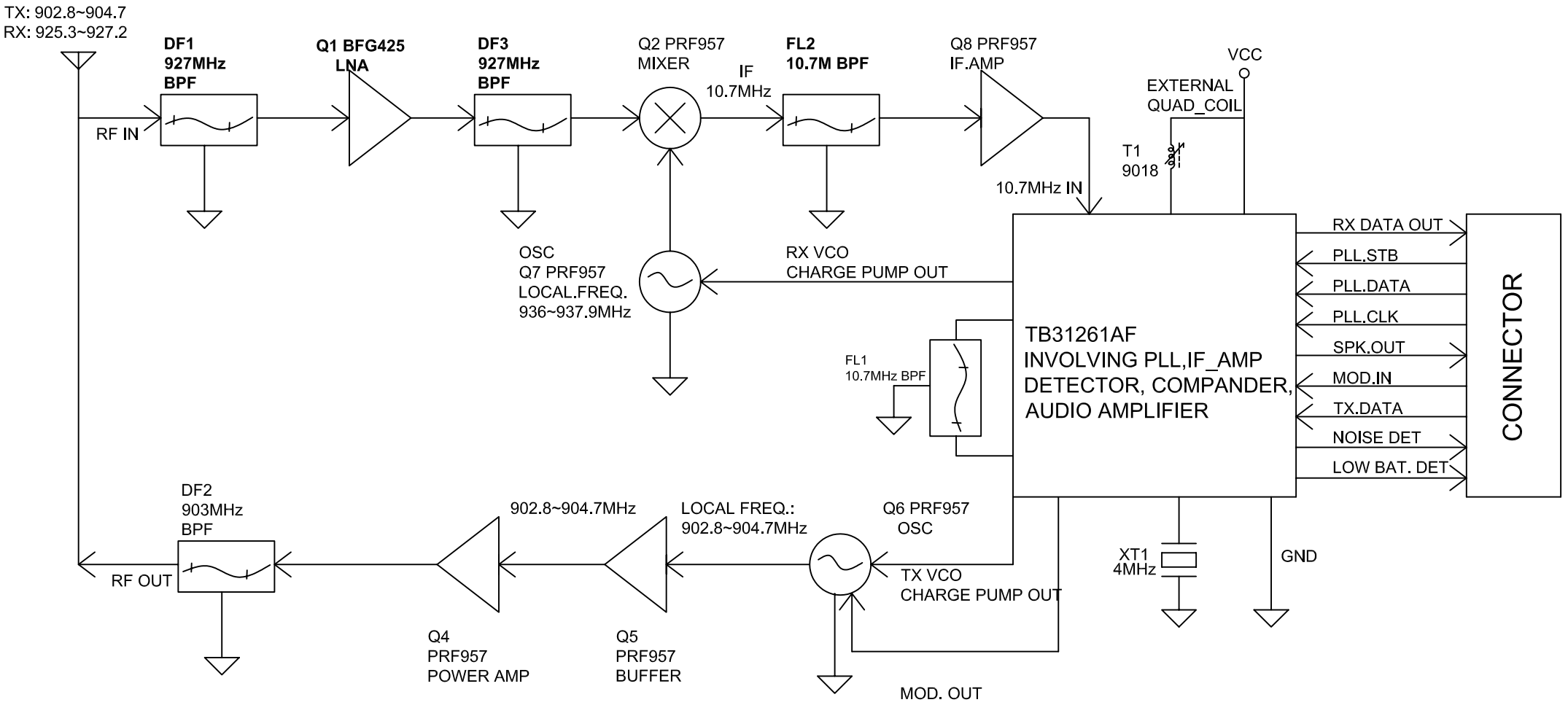
Base Description:

Varistor -protect circuit:	**The CSP301M is used to protect circuit.**
Memory	**E2PROM IC 24C03 for save register ID**
Speech network	**MC34018 is used for speech network**
MCU:	**The MCU is used to control the line interface, RF PLL and noise detect.**
900MHz RF Module:	**Toshiba IC TB31261 are used. This IC is included IF detector, PLL, and compander. Transmitter consisted of TX_VCO, TX buffer and power AMP. Receiver consisted of RX_VCO, LNA, MIXER and 1st IF_AMP.**
Voltage regulator:	**KA7805 is used to regulate the voltage.**
Antenna:	**It is using an inside 50ohm antenna, it permanently attached on RF module.**

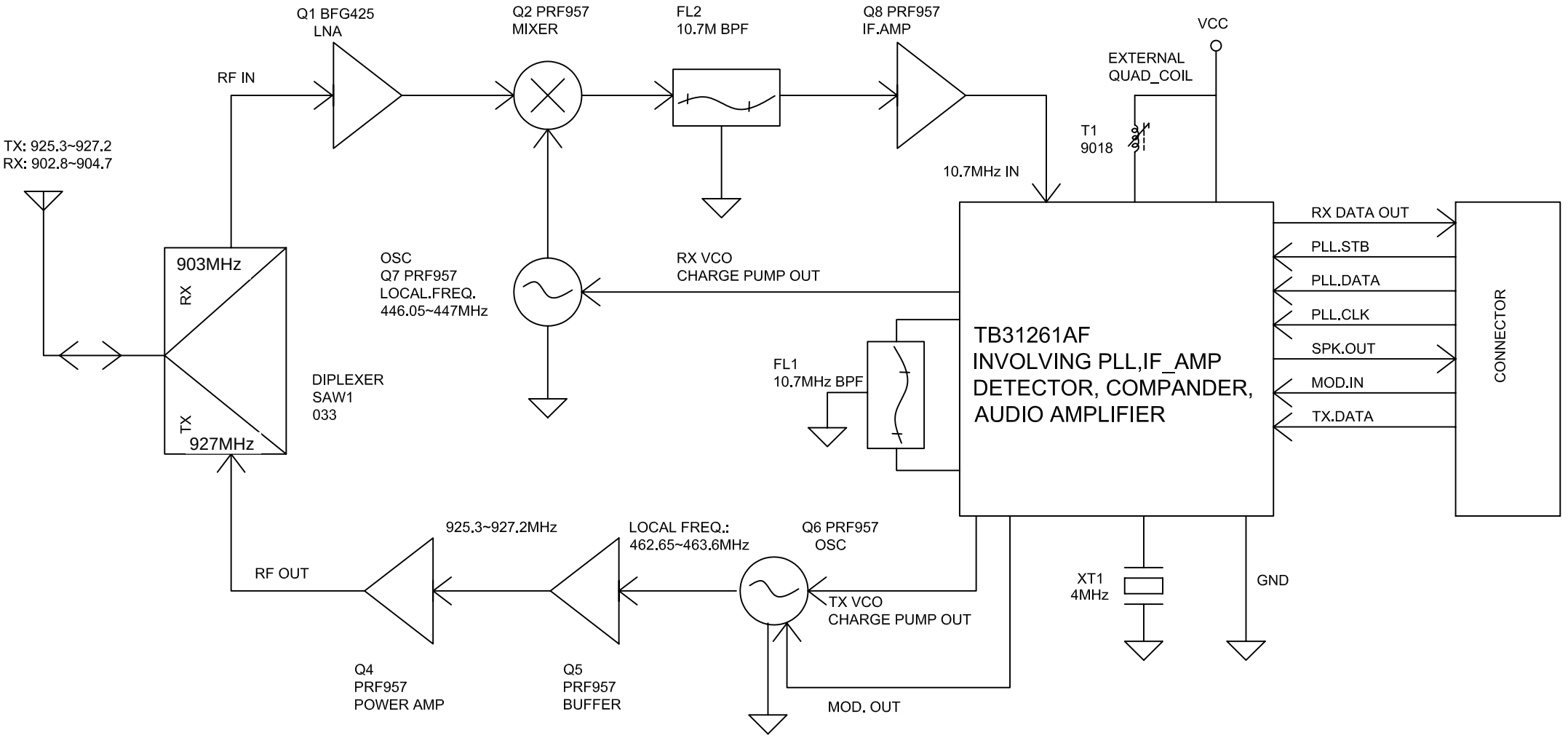
Handset Description:

Memory	**E2PROM IC 24C02 is use to save register IC.**
MCU:	**The MCU is used to control the keyboard, RF PLL and LOW BATTERY detect.**
900MHz RF Module:	**Toshiba IC TB31261 are used. This IC is included IF detector, PLL, and compander. Transmitter consisted of TX_VCO, TX buffer and power AMP. Receiver consisted of RX_VCO, LNA, MIXER and 1st IF_AMP.**
Antenna:	**It is using an inside 50ohm antenna, it permanently attached on RF module.**

30911 BASE RF BLOCK DIAGRAM



30911 HANDSET RF BLOCK DIAGRAM



30911 FREQUENCY TABLE

Unit: MHz

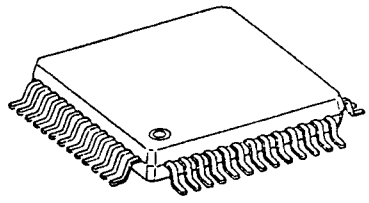
CH NO.	BASE		HANDSET	
	TX	RX	TX	RX
CH 1	902.800000	925.300000	925.300000	902.800000
CH 2	902.900000	925.400000	925.400000	902.900000
CH 3	903.000000	925.500000	925.500000	903.000000
CH 4	903.100000	925.600000	925.600000	903.100000
CH 5	903.200000	925.700000	925.700000	903.200000
CH 6	903.300000	925.800000	925.800000	903.300000
CH 7	903.400000	925.900000	925.900000	903.400000
CH 8	903.500000	926.000000	926.000000	903.500000
CH 9	903.600000	926.100000	926.100000	903.600000
CH 10	903.700000	926.200000	926.200000	903.700000
CH 11	903.800000	926.300000	926.300000	903.800000
CH 12	903.900000	926.400000	926.400000	903.900000
CH 13	904.000000	926.500000	926.500000	904.000000
CH 14	904.100000	926.600000	926.600000	904.100000
CH 15	904.200000	926.700000	926.700000	904.200000
CH 16	904.300000	926.800000	926.800000	904.300000
CH 17	904.400000	926.900000	926.900000	904.400000
CH 18	904.500000	927.000000	927.000000	904.500000
CH 19	904.600000	927.100000	927.100000	904.600000
CH 20	904.700000	927.200000	927.200000	904.700000

TENTATIVE · TOSHIBA Bi-COMS INTEGRATED CIRCUIT SILICON MONOLITHIC

TB31261AF

RF 1CHIP IC FOR 900MHz CORDLESS TELEPHONE

One packaging three systems PLL, IF detector, Compander. It is possible to reduce many external parts. This IC is suitable for radio section of 900MHz cordless telephone.



QFP52-P-1010-0.65

Weight : 0.45g (Typ.)

FEATURES

- Low operating voltage : V_{CC} = 2.7~5.5V
- PLL operating frequency : f = 400~1000MHz
- Serial control for all status
- Built-in clock output function for CPU
- Built in receiver amp
- Receiver output Level adjustment
- Variable battery alarm setting (4 thresholds)
- Built in battery saving function for intermittent receiving
- Small package:QFP52pin (0.65mm pitch)

Handle with care to prevent devices from deterioration by static electricity.

980910EBA1

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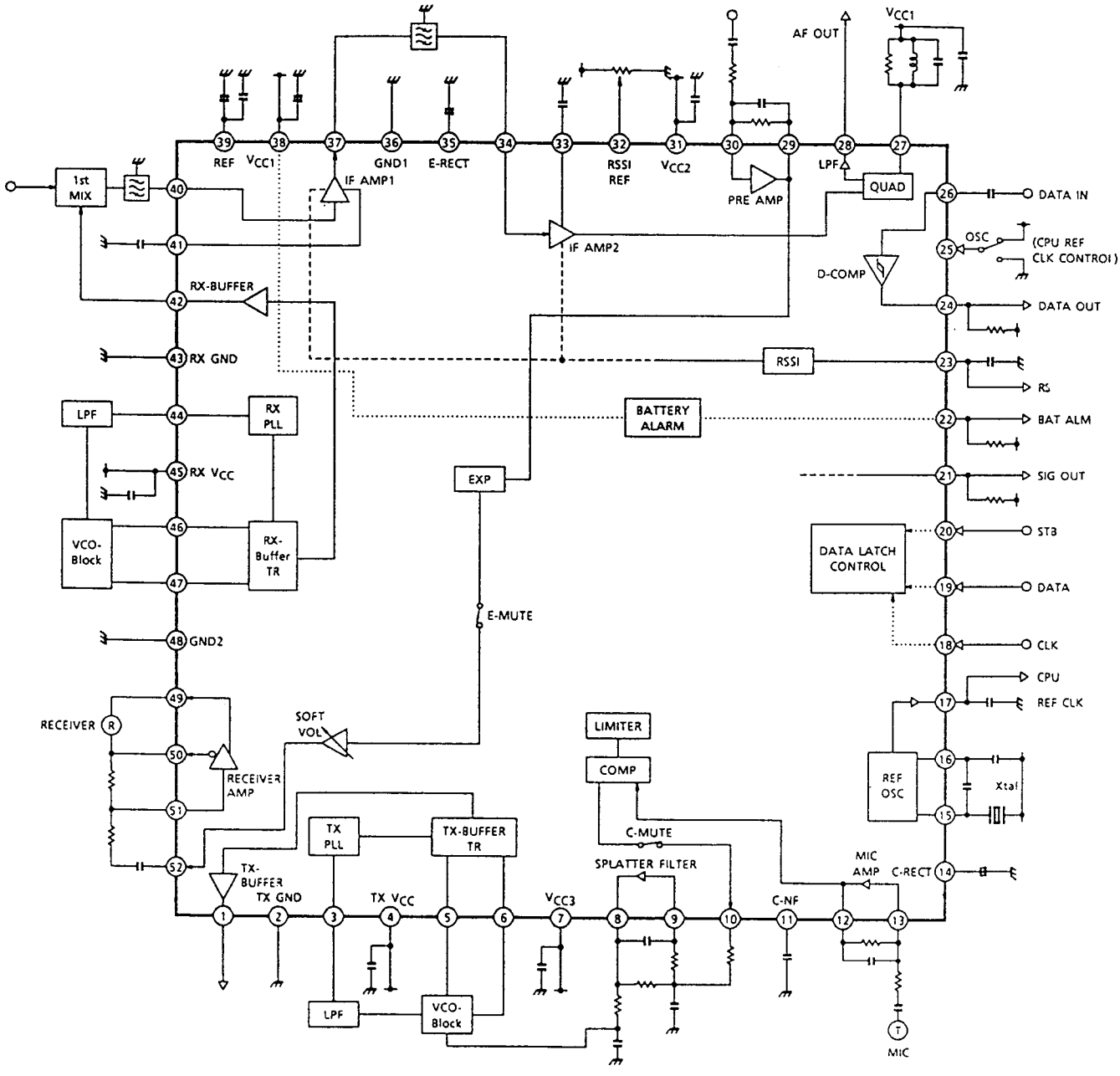
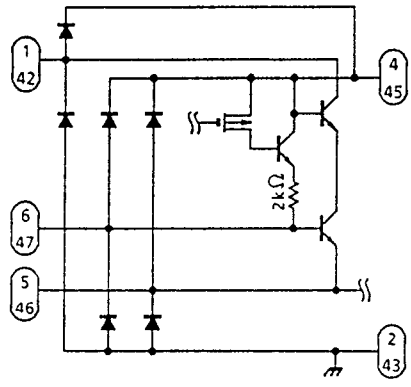
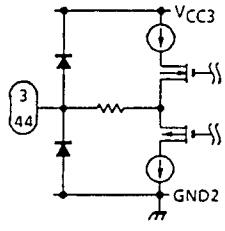
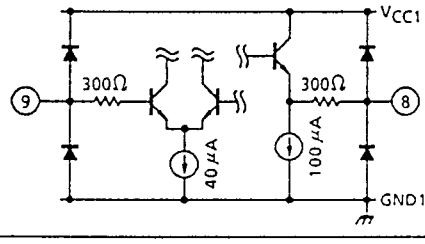
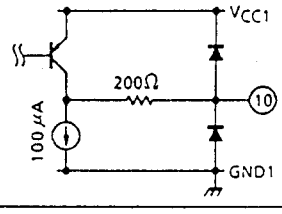
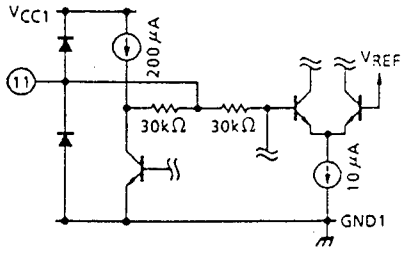
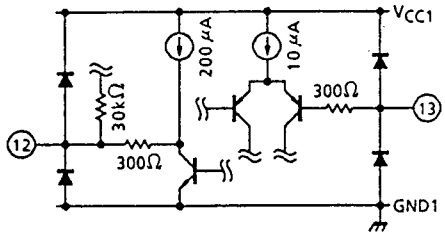
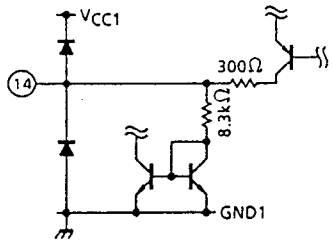
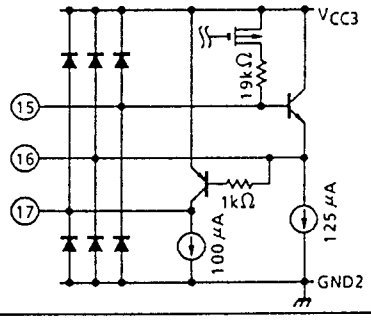
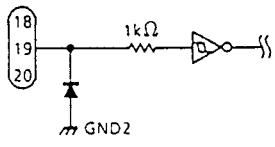
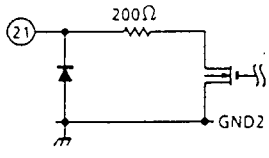
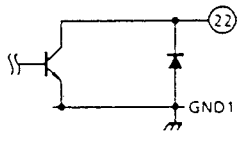
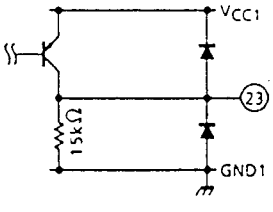
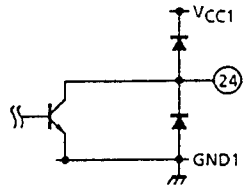
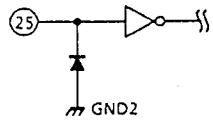
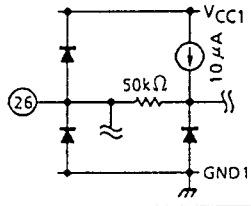
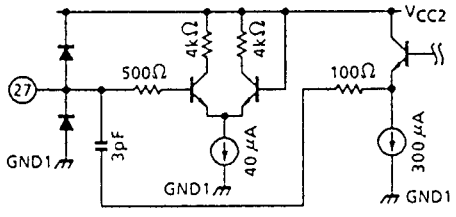
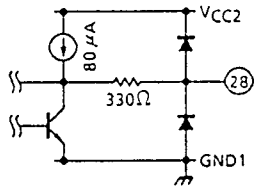
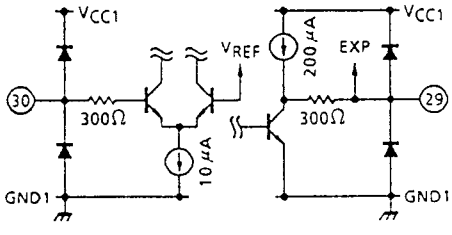
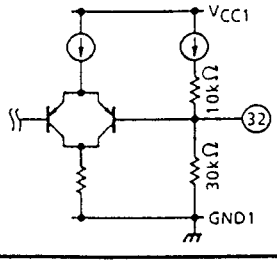
BLOCK DIAGRAM

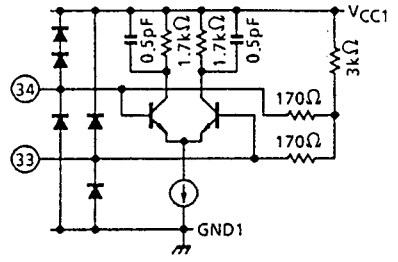
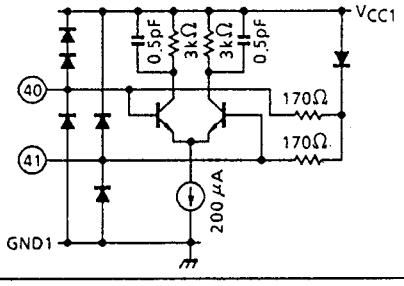
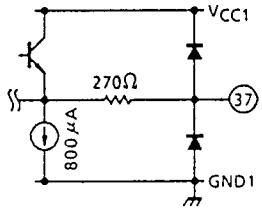
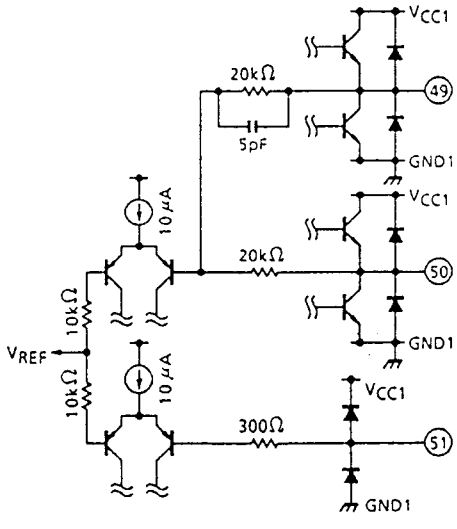


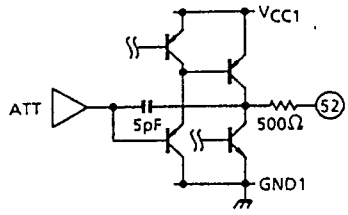
PIN FUNCTION (The value of resistor capacitor are typical)

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT
1	TX-OUT	Output terminal of TX frequency from TX-BUFFER TRANSISTOR.	
2	TX-GND	GND terminal.	
4	TX-V_{CC}	Power supply terminal.	
5	TX-Buffer E	Emitter terminal of TX-BUFFER TRANSISTOR.	
6	TX-Buffer B	Base terminal of TX-BUFFER TRANSISTOR.	
42	RX-OUT	Output terminal of RX frequency from RX-BUFFER TRANSISTOR.	
43	RX-GND	GND terminal.	
45	RX-V_{CC}	Power supply terminal.	
46	RX-Buffer E	Emitter terminal of RX-BUFFER TRANSISTOR.	
47	RX-Buffer B	Base terminal of RX-BUFFER TRANSISTOR.	
3	TX-CP	Output terminal of CHARGE PUMP. CHARGE PUMP circuit outputs constant current which is varied by serial data.	
44	RX-CP	Output terminal of CHARGE PUMP. CHARGE PUMP circuit outputs constant current which is varied by serial data.	
7	V_{CC3}	Power supply terminal.	—
8	SPLATTER-OUT	Output of Splatter Filter. And connected to Input of COMPRESSOR.	
9	SPLATTER-IN	Output of SPLATTER FILTER.	
10	COMP-OUT	Output of COMPRESSOR.	
11	C-NF	Feedback circuit of T type is formed by external capacitor with SUM AMP.	

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT
12	MIC-OUT	Output of MIC AMP and connected directly to Input of COMPRESSOR.	
13	MIC-IN	Input terminal of MIC AMP.	
14	C-RECT	Connected capacitor for foll-wave rectifier circuit of COMPRESSOR.	
15	REF-OSC1	REFERENCE OSCILLATOR input and output terminals. Colpitts oscillator is formed by internal emitter follower and external X'tal.	
16	REF-OSC2		
17	OSC-OUT	Output terminal of BUFFER AMP. Output signal for MPU clock.	
18	CLK	Input terminal of clock. Input the serial data control for this IC.	
19	DATA	Input terminal of data.	
20	STB	Input terminal of strobe signal.	
21	SIG-OUT	Output terminal of detection signal. It is the open drain output.	
22	BAT-ALM	BATTERY ALARM terminals. When V_{CC} decrease VBAT-L, this terminal outputs "H"Level. Detection voltage is controled by data bit. This terminal is open collector output.	
23	RSSI	This terminal outputs DC voltage level according to input signal level of IF AMP. Dynamic range is around 80dB.	

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT
24	DATA-OUT	Output terminal of ware from shaping circuit. This terminal is open collector output.	
25	OSC	Control terminal for REF CLK output. When voltage of this terminal is GND then whether REF CLK output or not is controlled by serial data setting, when voltage of this terminal is V_{CC} then REF CLK always output regardless of serial data setting.	
26	D-COMP-IN	DATA COMPARATOR input terminal. This terminal input demodulated signal of DATA.	
27	QUAD	Phase shift signal input terminal of FM demodulator.	
28	AF-OUT	Demodulated signal output terminal. Carrier leak is small as LPF is built-in.	
29	PRE-OUT	Output terminal from PRE-AMP.	
30	PRE-IN	Input terminal to PRE-AMP.	
31	V_{CC2}	Power supply terminal.	—
32	RSSI-REF	DC voltage input terminal to control detection level of RSSI COMPARATOR.	

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT
33	IF2-REF	IF AMP2 input and decoupling input for bias.	
34	IF2-IN		
40	IF1-IN	IF AMP1 input and decoupling input for bias.	
41	IF1-REF		
35	E-RECT	Terminal for rectifier of EXPANDER. Almost the same circuit as C-RECT terminal.	—
36	GND1	GND terminal.	—
37	IF-OUT	Output terminal of IF AMP.	
38	V_{CC1}	Power supply terminal.	—
39	REF	Reference terminal through internal buffer of compander block.	—
48	GND2	GND terminal.	—
49	RECEIVER 1	Receiving output for a dynamic receiver. Used for BTL output type, RO1 terminal and RO2 terminal.	
50	RECEIVER 2		
51	RECEIVER-IN	Inverted input of RECEIVER AMP.	

PIN No.	PIN NAME	FUNCTION	INTERNAL EQUIVALENT CIRCUIT
52	EXP-OUT	Output of SUM amp at EXPANDER. The signal from gain cell is gained by inverted amp. The gain level can be controlled by software.	

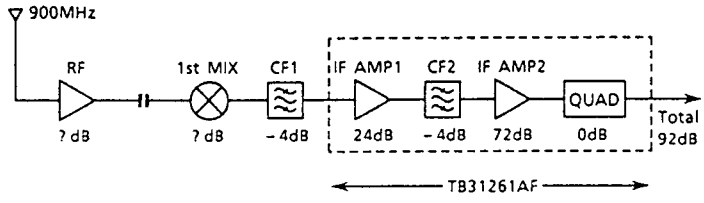
1. General Description

TB31261F is controlled all status by serial data. This IC is included IF detector, PLL and compander. IF detector function is wideband system, dual PLL function (~1000MHz), and compander with MIC AMP and RECEIVER AMP.

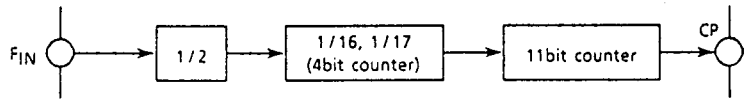
POWER SUPPLY BLOCK ASSIGN

V_{CC1}	GND1	IF-AMP1, IF-AMP2, DATA-COMP, RSSI, BATTERY-ALARM, SOFT-VOLUME, MIC-AMP, COMPRESSOR, SPLATTER-FILTER, PRE-AMP, EXPANDER, RECEIVER-AMP
V_{CC2}		IF-AMP2, QUAD
V_{CC3}	GND2	RX-PLL, TX-PLL, REF-OSC, DATA LATCH CONTROL
RX-V_{CC}	RX-GND	RX-PRESCALER, RX-BUFFER, RX-BUFFER TR
TX-V_{CC}	TX-GND	TX-PRESCALER, TX-BUFFER, TX-BUFFER TR

2. Gain Distribution for Receiving



3. PLL Block

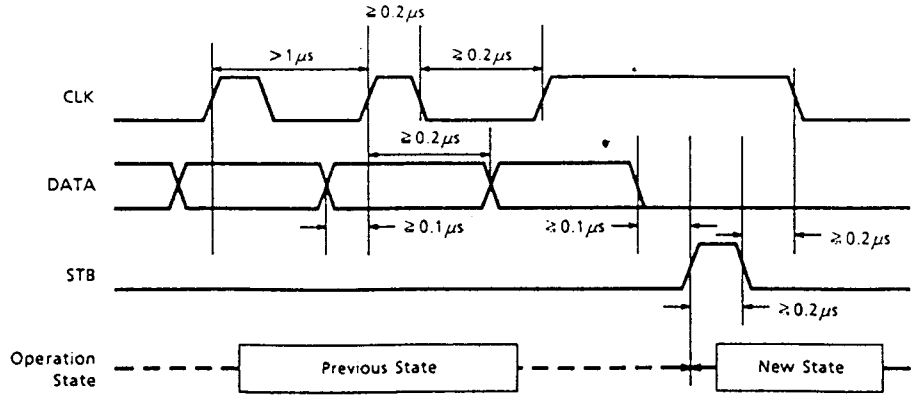


4. Data Latch Control

This block has 4 registers assigned by 2 or 3 bits CODE.DATA is read on the time of up edge of CLK. When STB receivers high signal, DATA in shift register is sent into LATCH to control block which CODE indicates and the operation starts.

INPUT TIMING FOR SERIAL DATA

When both CLK "H" and DATA "L", STB "H" leads data active.



Code Assign

CODE			CONTROL BLOCK	FUNCTION
*	1	0	TX divider (18bits)	Setting frequency for TX-PLL
*	0	1	RX divider (18bits)	Setting frequency for RX-PLL
*	1	1	REF divider (12bits)	Setting phase comparison frequency
0	0	0	Option control 1	Battery save, Mute control, BAT-ALM, etc
1	0	0	Option control 2	Volume control

Serial Data Format

(1) TX DIVIDER

Swallow Counter (4bit)				Programmable Counter (11bit)												CODE	
A0	A1	A2	A3	M0	M1	M2	M3	M4	M5	M6	M7	M8	M9	M10	*	1	0

←1st ↑STB

* Don't care

N = 2 × (16M + A) (480 – 65534)

A = A0 + 2A1 + 4A2 + 8A3

M = M0 + 2M1 + 4M2 + 8M3 + 16M4 + 32M5 + 64M6 + 128M7 + 256M8 + 512M9 + 1024M10

(2) RX DIVIDER

Swallow Counter (4bit)				Programmable Counter (11bit)												CODE	
A0	A1	A2	A3	M0	M1	M2	M3	M4	M5	M6	M7	M8	M9	M10	*	0	1

←1st ↑STB

* Don't care

N = 2 × (16M + A) (480 – 65534)

A = A0 + 2A1 + 4A2 + 8A3

M = M0 + 2M1 + 4M2 + 8M3 + 16M4 + 32M5 + 64M6 + 128M7 + 256M8 + 512M9 + 1024M10

(3) REF DIVIDER

Programmable Counter (10bit)										CODE	
R0	R1	R2	R3	R4	R5	R6	R7	R8	R9	1	1

←1st ↑STB

N = R (4 – 1023)

R = R0 + 2R1 + 4R2 + 8R3 + 16R4 + 32R5 + 64R6 + 128R7 + 256R8 + 512R9

(4) Option Control 1

SIG OUT			REF	TX Control				RX Control				BAT-ALM			CODE		
TXLD	RXLD	RSSI	XOSC	RF	AF	CP	MUT	RF	AF	CP	MUTE	BA1	BA2	BA3	0	0	0

←1st ↑STB

1. Battery Saving Control

0	Operation
1	Battery Saving

BIT	CONTROL BLOCK
RX-RF	RX-PLL, RX-BUFFER TR, IF AMP, QUAD, DATA COMP, RSSI
RX-AF	PRE AMP, EXPANDER, RECEIVER AMP
TX-RF	TX-PLL, TX-BUFFER TR
TX-AF	MIC AMP, COMPRESSOR, SPLATTER-FILTER
REF-OSC	REF-OSC

2. Charge Pump Output Current Select

CP	Current
0	400μA
1	800μA

3. Mute Control

0	Operation
1	Mute On

TX-MUTE control for COMPRESSOR output.
RX-MUTE control for EXPANDER output.

4. BATTERY ALARM Detection Setting

This IC has 4 threshold levels for detection of battery dropping.
These threshold levels are given by below table.

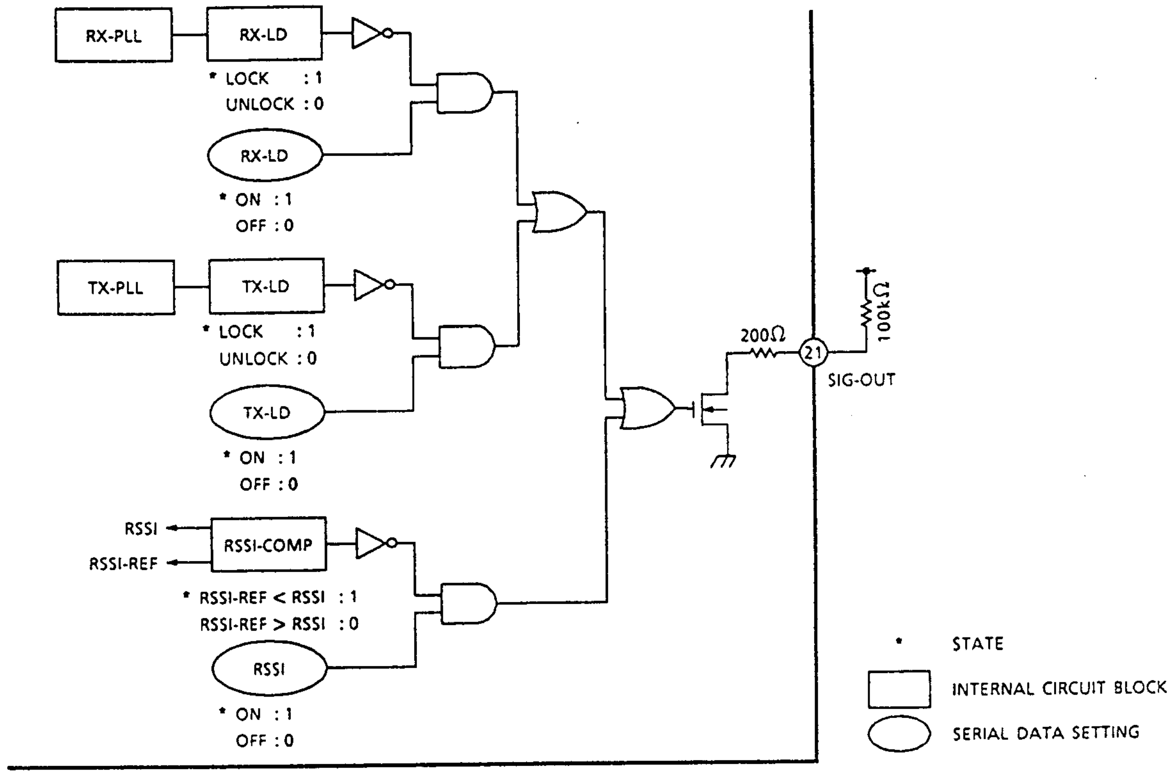
BA1	BA2	BA3	DET.VOLTAGE	BAT-ALM Out Put	
				DET.VOL > Vcc	DET.VOL < Vcc
0	0	1	3.00v	H	L
0	1	0	3.15v	H	L
0	1	1	3.30v	H	L
1	0	0	3.45v	H	L
1	1	1	BS	H	

5. SIG OUT Selection

SIG OUT terminal generates combination states of RX and TX LOCK DETECTOR and RSSI.
IF you set plual BIT to 1, then SIG OUT is "AND" output of each FUNCTION.

0	OFF
1	OUT PUT

BIT	FUNCTION
TXLD	TX-PLL LOCK DETECTOR
RXLD	RX-PLL LOCK DETECTOR
RSSI	RSSI COMPARATOR OUTPUT



		STATE																															
INPUT: SERIAL DATA SETTING	RX-LD	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1
	TX-LD	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	1
	RSSI	0	0	0	0	1	1	1	1	0	0	0	0	1	1	1	1	0	0	0	0	1	1	1	1	0	0	0	0	1	1	1	1
INPUT: CIRCUIT STATE	RX-LD	0	0	0	0	0	0	0	0	1	1	1	1	1	1	1	1	0	0	0	0	0	0	0	0	1	1	1	1	1	1	1	1
	TX-LD	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1
	RSSI	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
OUTPUT	SIG-OUT	H	L	L	L	L	L	L	L	H	H	L	L	L	L	L	L	H	L	H	L	L	L	L	L	H	H	H	H	L	L	L	L

		STATE																															
INPUT: SERIAL DATA SETTING	RX-LD	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	1
	TX-LD	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	1	0	0	1	1
	RSSI	0	0	0	0	1	1	1	1	0	0	0	0	1	1	1	1	0	0	0	0	1	1	1	1	0	0	0	0	1	1	1	1
INPUT: CIRCUIT STATE	RX-LD	0	0	0	0	0	0	0	0	1	1	1	1	1	1	1	1	0	0	0	0	0	0	0	0	1	1	1	1	1	1	1	1
	TX-LD	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1
	RSSI	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1
OUTPUT	SIG-OUT	H	L	L	L	H	L	L	L	H	H	L	L	H	H	L	L	H	L	H	L	H	L	H	L	H	H	H	H	H	H	H	H

(5) Option Control 2

RECEIVER OUTPUT LEVEL CONTROL

It is possible to volume control to set these bits.

And this resister includes TEST bits which must be set 0 in customer side.

1.5dB steps from 0dB to −22.5dB.

Receiver Volume					CODE		
VOL1	VOL2	VOL3	VOL4	*	1	0	0

* You have to be sure to set 0.

VOL1	VOL2	VOL3	VOL4	GAIN
0	0	0	0	0dB
0	0	0	1	−1.5dB
0	0	1	0	−3.0dB
0	0	1	1	−4.5dB
0	1	0	0	−6.0dB
0	1	0	1	−7.5dB
0	1	1	0	−9.0dB
0	1	1	1	−10.5dB
1	0	0	0	−12.0dB
1	0	0	1	−13.5dB
1	0	1	0	−15.0dB
1	0	1	1	−16.5dB
1	1	0	0	−18.0dB
1	1	0	1	−19.5dB
1	1	1	0	−21.0dB
1	1	1	1	−22.5dB

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Power Supply Voltage	V_{CC}	6	V
Power Dissipation	P_D	900 *1	mW
Operating Temperature	T_{opr}	−20~70	°C
Storage Temperature	T_{stg}	−50~150	°C

*1 IC single unit

TENTATIVE ELECTRICAL CHARACTERISTICS

TOTAL CHARACTERISTIC (V_{CC} = 3.6V, Ta = 25°C, Δf = 25kHz, fmod = 1kHz)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Power Supply Voltage	V_{CC} (opr)	—	—	2.7	3.6	5.5	V
Consumption Current 1	I_{CC1}	1	ALL ON (Not including VCO current)	12.3	24.6	33.3	mA
Consumption Current 2	I_{CC2}	1	RX-RF ON (Not including VCO current)	7.7	11.6	15.7	mA
Consumption Current 3	I_{CC3}	1	RX-AF ON	2.4	3.5	4.8	mA
Consumption Current 4	I_{CC4}	1	TX-RF ON (Not including VCO current)	2.6	7.1	9.6	mA
Consumption Current 5	I_{CC5}	1	TX-AF ON	0.8	2.1	2.9	mA
Alarm Supply Current	I_{CC} (A)	1	RL = 100kΩ V_{BAT-L} = 3.30V端子	—	160	200	μA
Supply Current at BS	I_{CC} (BS)	1	ALL OFF	—	0	50	μA
V_{REF} Voltage	V_{REF}	1	—	1.0	1.45	1.8	V
Data Input Threshold	V_{IH}	—	—	0.8 × V_{CC}	V_{CC}	5.5	V
	V_{IL}	—	—	−0.2	0	0.2 × V_{CC}	
Data Input Current	I_{IH}	—	V_{IH} = V_{CC}	—	0	1	μA
	I_{IL}	—	V_{IL} = GND	—	0	1	
CK Input Frequency	f_{CK}	—	—	—	100	1000	kHz

DETECTOR SECTION (Unless Otherwise Specified, V_{CC} = 3.6V, Ta = 25°C)
BATTERY ALARM

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Detection Voltage 1	V_{BAT-L}	1	—	2.85	3.00	3.15	V
	V_{BAT-H}		—	—	3.08	3.23	
Detection Voltage 2	V_{BAT-L}	1	—	2.99	3.15	3.31	V
	V_{BAT-H}		—	—	3.25	3.41	
Detection Voltage 3	V_{BAT-L}	1	—	3.14	3.30	3.47	V
	V_{BAT-H}		—	—	3.40	3.57	
Detection Voltage 4	V_{BAT-L}	1	—	3.28	3.45	3.62	V
	V_{BAT-H}		—	—	3.55	3.73	
Output Low Level Voltage	V_{OL1}	1	I_{SINK} = 0.1mA		0.1	0.3	V
Output Leak Current	I_{LEAK1}	1	V_{ALM} = 3.6V		0	5	μA

DATA COMPARATOR

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Minimum Detection Level	V_{TH1}	2	f = 500Hz	—	—	50	mVrms
Output Low Level Voltage	V_{OL2}	1	I_{SINK} = 0.2mA	—	0.1	0.3	V
Output Leak Current	I_{LEAK2}	1	H Level	—	0	5	μA
Duty Ratio	Duty	2	V_{IN} (Data comparator input) = 120mVrms, "H" Level, F = 1kHz	44	—	56	%

SIG OUT DETECTION

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Low Level Voltage	V_{OL3}	1	I_{SINK} = 0.2mA	—	0.1	0.5	V
Output Leak Current	I_{LEAK3}	1	SIG out off mode	—	0	5	μA

PLL SECTION (Unless Otherwise Specified, V_{CC} = 3.6V, Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
PLL Operating Frequency	f_{IN}	1	—	400	900	1000	MHz
PLL Input Sensitivity	V_{IN}	1	—	90	103	110	dBμV
XIN Operating Frequency	f_{XIN}	1	V_{IN} = 110dBμV	2	4	24	MHz
XIN Input Sensitivity	V_{XIN}	1	f_{IN} = 4MHz	100	110	115	dBμV
Charge Pump Output Current	I_{CP1}	—	V_{CP} = 1.8V	—	± 400	—	μA
	I_{CP2}	—	V_{CP} = 1.8V	—	± 800	—	
Charge Pump Leak Current	I_{LEAK4}	1	—	—	0	5	μA

RECEIVING SECTION (V_{CC} = 3.6V、 Ta = 25°C、 Δf = 25kHz、 fmod = 1kHz)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
12dB SINAD Sensitivity	12dB SINAD	—	INPUT 50Ω	—	13.5	—	dBμVEMF
IF AMP1 Gain	GIF1	2	—	—	24	—	dB
IF AMP2 Gain	GIF2	—	—	—	72	—	dB
Demodulated Output level	V_{OD}	2	V_{IN} (IF1) = 70dBμVEMF	90	117	144	mVrms
S/N Ratio	SN	2	V_{IN} (IF1) = 70dBμVEMF	50	69.5	—	dB
AM Rejection Ratio	AMR	2	V_{IN} (IF1) = 70dBμVEMF	—	68.3	—	dB
IFAMP1 input Resistance	RIF1IN	—	IF1-IN	—	330	—	Ω
IFAMP1 Output Resistance	RIF1OUT	—	IF1-OUT	—	330	—	Ω
IFAMP2 Input Resistance	RIF2IN	—	IF2-IN	—	330	—	Ω
RSSI Output Voltage	VRSSI1	2	V_{IN} (IF1-IN) = 20dBμVEMF	0.15	0.35	0.50	V
	VRSSI2	2	V_{IN} (IF1-IN) = 70dBμVEMF	1.36	1.70	2.06	

AUDIO SECTION (Unless Otherwise Specified, V_{CC} = 3.6V, f_{in} = 1kHz, Ta = 25°C)
MIC AMP + COMPRESSOR

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
COMP Input Reference Level	V_{refC}	2	V_{OM} = −10dBV	−11.3	−9.1	−7.3	dBV
COMP Output Deviation	V_{OC}	2	V_{OM} = −30dBV	−0.7	−0.1	+0.7	dB
MIC AMP Voltage Gain Setting Range	VGR_M	—		—	0	—	dB
Total Harmonic Distortion	THD_C	2	V_{OM} = −10dBV	—	0.3	1	%
Output Noise Level	V_{NOC}	2	Input-GND Short	—	−62	−48	dBV
Limitting Level	V_{lim1}	—	COMP OUT, V_{IM} = 0dBV	—	1.3	—	Vp-p
	V_{lim2}	—	MIC OUT, V_{IM} = 0dBV	—	2.5	—	
MUTE Output Level	V_{MUTE}	—	—	—	−90	—	dBV
Crosstalk EC	CT_{EC}	—	V_{IP} = 0dBV	—	−36.7	—	dBV
Attack Time	T_{AC}	—	V_{IM} = −46 → −34dBV	—	3.5	—	ms
Recovery Time	T_{RC}	—	V_{IM} = −34 → −46dBV	—	5.0	—	ms

PRE AMP + EXPANDER + RECEIVER AMP

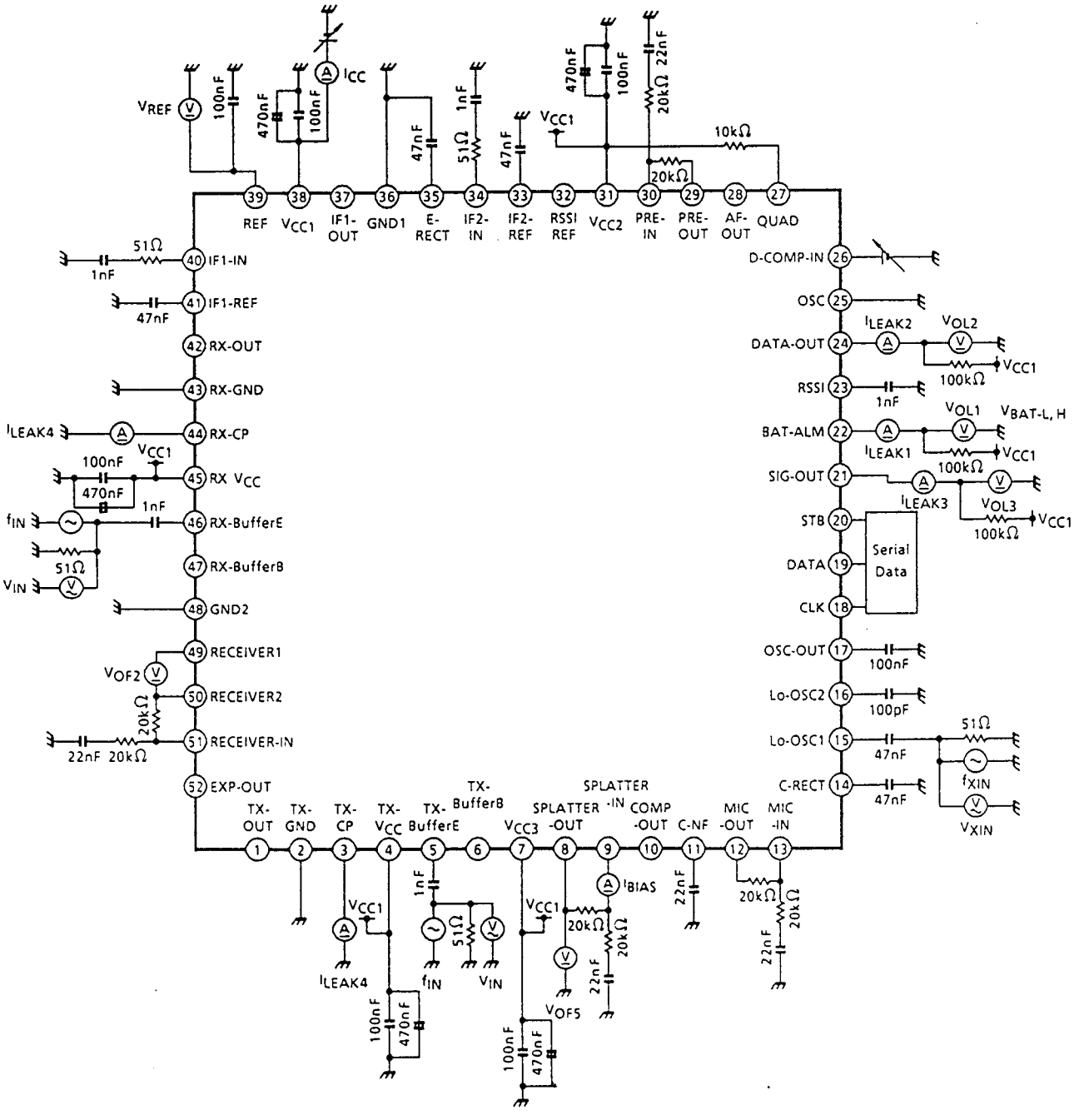
CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
EXP Input Reference Level	V_{refE}	2	V_{OP} = −10dBV	−13.6	−10.9	−8.0	dBV
EXP Output Deviation	V_{OE}	2	V_{OP} = −35dBV	−1.0	+0.3	+1.8	dB
RO1 Voltage Gain	G_{RO1}	—	R_L = 150Ω	—	6	—	dB
Total Harmonic Distortion	THD1	2	R_L = 150Ω, V_{RI} = −15dBV	—	0.65	1.5	%
Output Noise Level	V_{NOR}	2	Input-GND Short	—	−76	−65	dBV
Maximum Output Level	D_R	2	THD = 3%, 150Ω load	—	2.63	—	Vp-p
MUTE Output Level	V_{MUTE}	—	—	—	−65	—	dBV
PRE AMP Voltage Gain Setting Range	VGR_P	—	—	0	—	20	dB
RECEIVER AMP Voltage Gain Setting Range	VGR_R	—	—	6	—	20	dB
Offset Voltage	V_{OF2}	1	RO1·RO2	−50	0	50	mV
Crosstalk CE	CT_{CE}	—	V_{IM} = −20dBV	—	−79	—	dB
Attack Time	T_{AE}	—	V_{IP} = −18 → −12dBV	—	8.5	—	ms
Recovery Time	T_{RE}	—	V_{IP} = −12 → −18dBV	—	4.5	—	ms

FILTER AMP

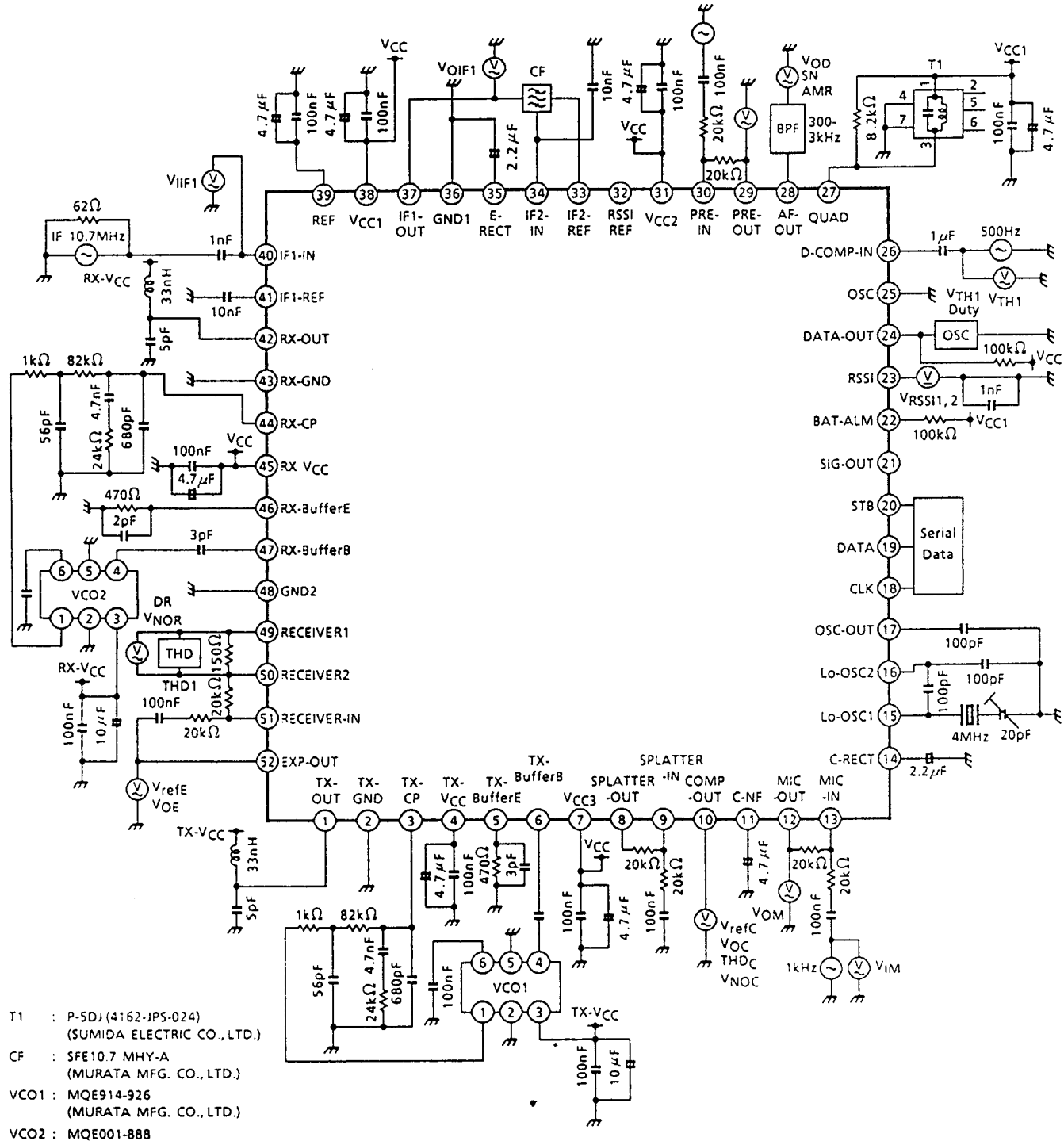
CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Voltage Gain	G5	—	—	—	0	—	dB
Maximum Output Level	D_{R5}	—	THD = 3%	—	3	—	Vp-p
Input Bias Current	I_{BIAS}	1	—	—	1.5	2.5	μA
Offset Voltage	V_{OF5}	1	—	−35	0	35	mV

* This specification is target value

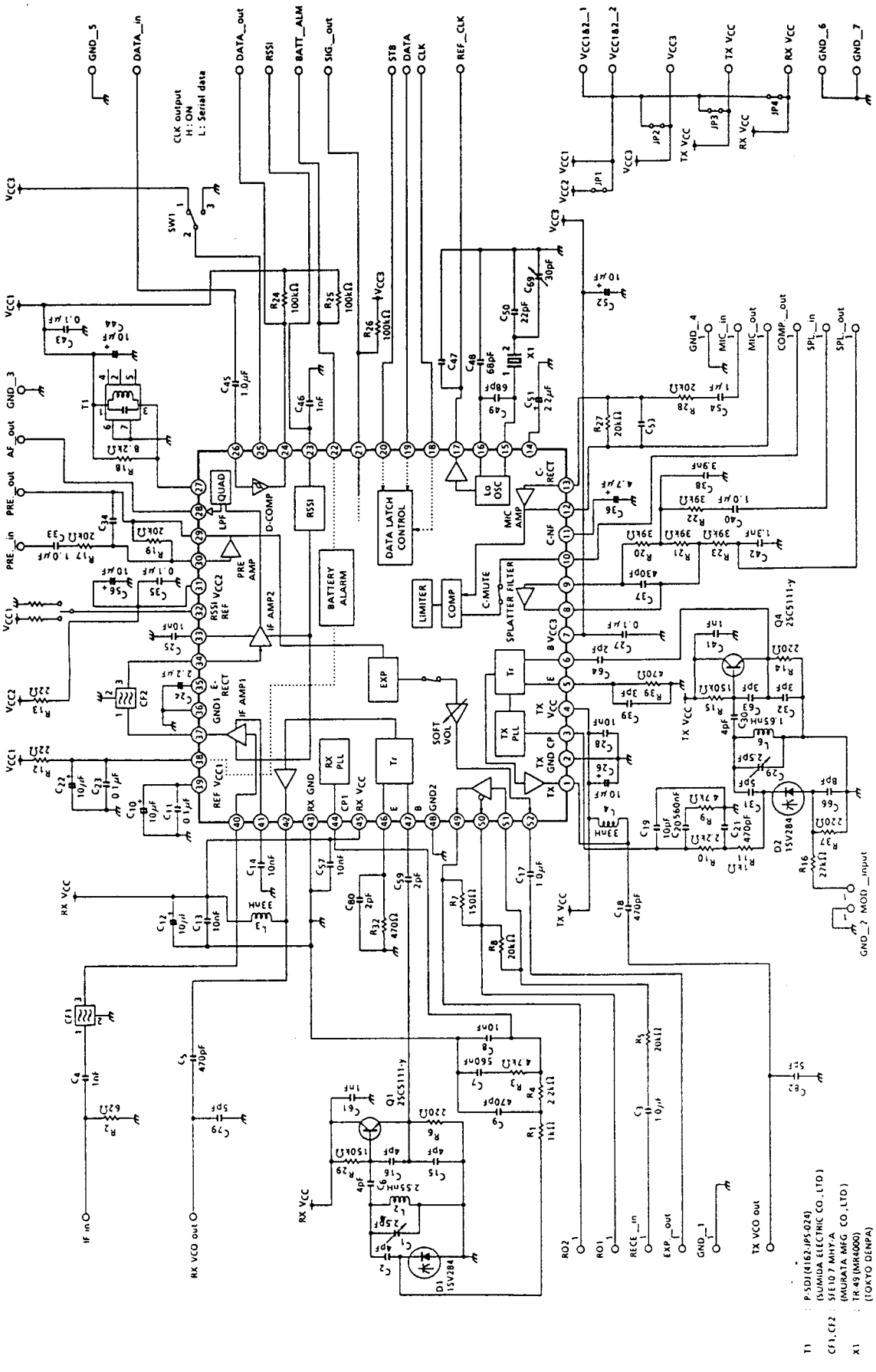
TEST CIRCUIT 1



TEST CIRCUIT 2

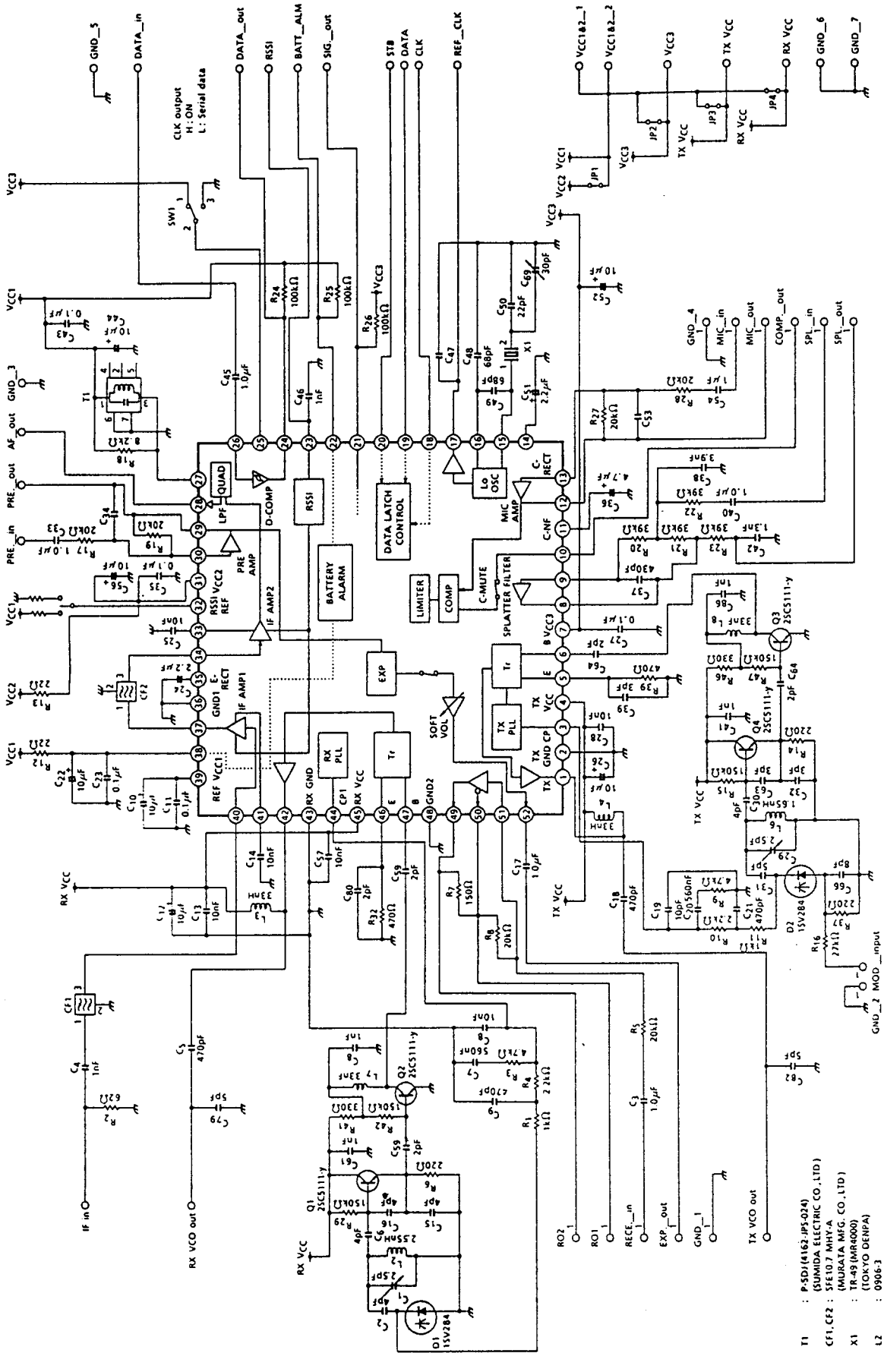


APPLICATION CIRCUIT 1



T1 : P-5D1(4162-JPS024) (SUMIDA ELECTRIC CO., LTD)
CF1, CF2 : SFE10.7 MHY-A (MURATA MFG. CO., LTD)
X1 : TR-49 (MR4000) (TOKYO DENPA)
L2 : 0906-3 (Coilcraft)
L6 : 0906-2 (Coilcraft)

APPLICATION CIRCUIT 2



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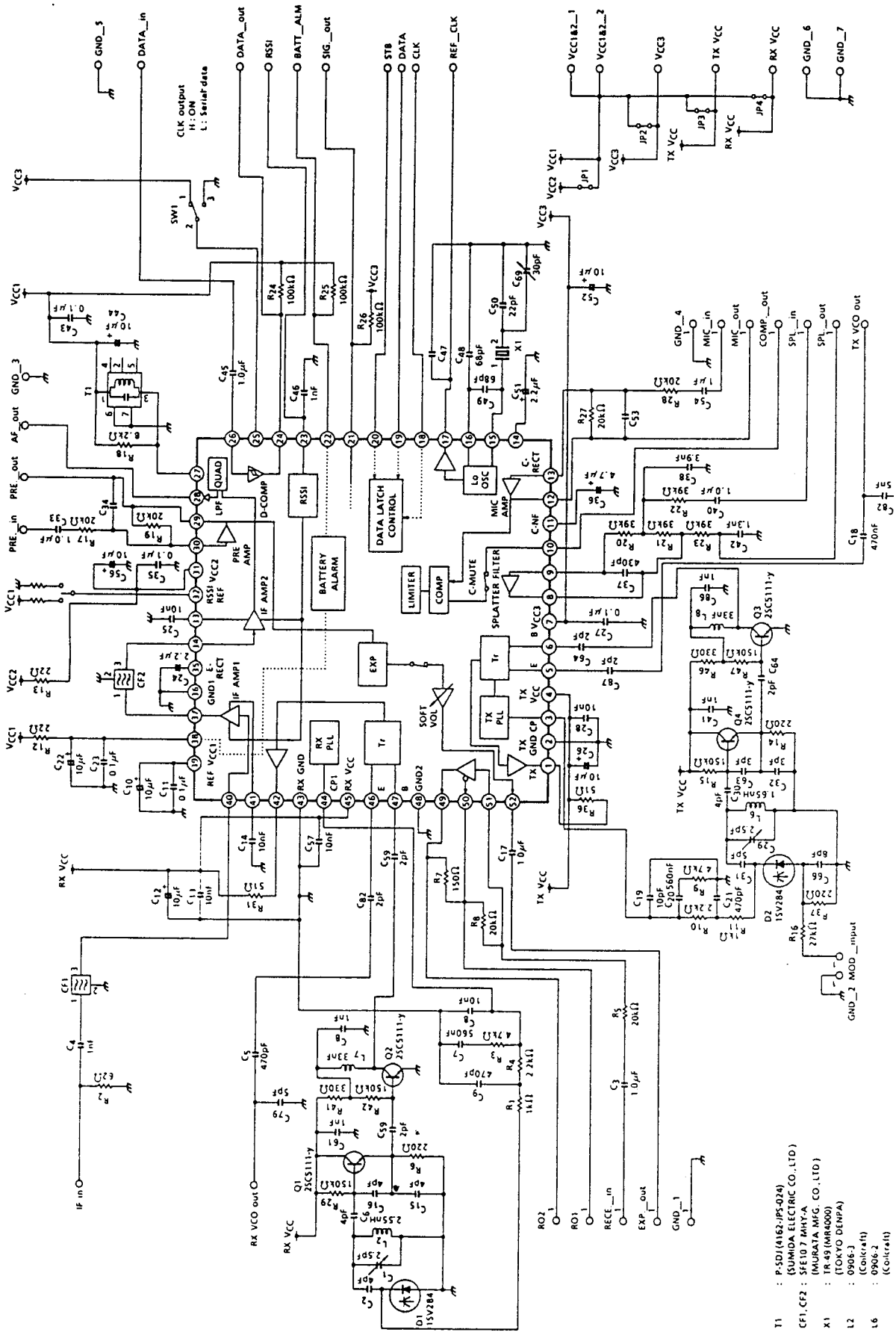
CF1, CF2 : SFE10.7 MHY-A (MURATA MFG. CO.,LTD)
X1 : TR-49(MR4000) (TOKYO DENPA)
L2 : 0906-3 (Coilcraft)
L6 : 0906-2 (Coilcraft)

APPLICATION CIRCUIT 3

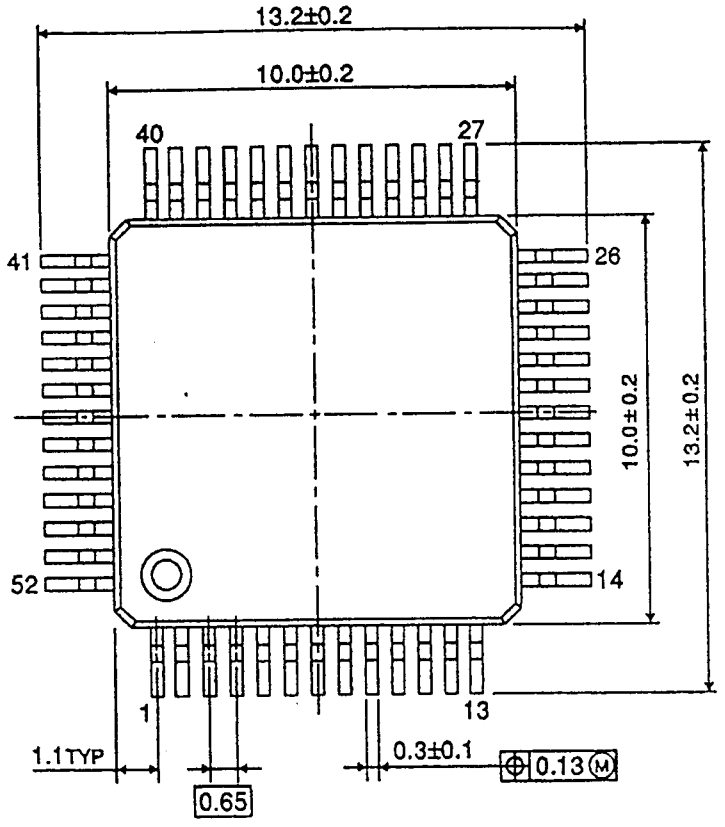


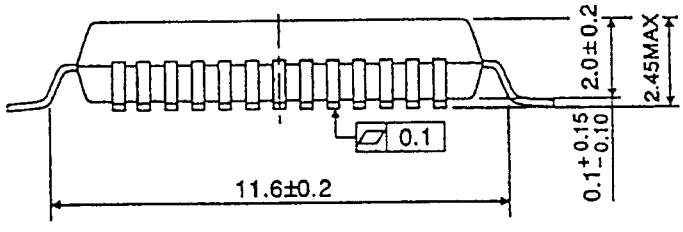
T1 : P-5DJ (4162-JPS-024) (SUMIDA ELECTRIC CO.,LTD)
CF1, CF2 : SFE10.7 MHY-A (MURATA MFG. CO.,LTD)
X1 : TR-49 (MR4000) (TOKYO DENPA)
L2 : 0906-3 (Coilcraft)
L6 : 0906-2 (Coilcraft)

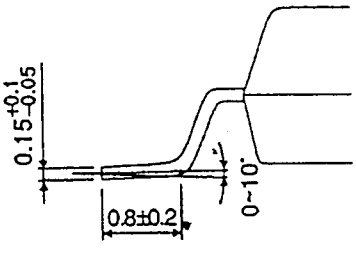
OUTLINE DRAWING

QFP52-P-1010-0.65

Unit : mm







Weight : 0.45g (Typ.)